Offset Cancelling Circuit

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Abstract—A monolithic offset cancelling circuit to reduce the offset voltage at an integrated audio-amplifier output is described. This offset voltage is detected using a low-pass filter with a very large time constant for which only one small on-chip capacitor is needed. The circuit was realized with a bipolar cell-based semicustom array.

Measurements have shown that a -3 -dB bandwidth below 5 Hz can be realized with a capacitor value of 50 pF. The resulting offset voltage at the audio-amplifier output was 2.5 mV. The offset cancelling circuit increases the wide-band noise voltage at the audio-amplifier output by 0.15-mV rms over the frequency range of 10 Hz to 30 kHz.

The use of the offset cancelling circuit eliminates the need for a large external electrolytic capacitor. If an audio amplifier with a single supply voltage is used, a second electrolytic capacitor, needed to obtain a stable reference at half the supply voltage, can be eliminated.

I. INTRODUCTION

IN MOST integrated audio amplifiers the closed-loop gain is defined by a resistor ratio in the feedback loop as shown by Fig. 1. A problem is that the gain for an unwanted dc offset voltage equals the ac gain. Usually a capacitor is used to eliminate the dc gain as shown. However, large capacitor values are needed which cannot be integrated. Therefore there is a need for a fully integrated circuit that is capable of reducing the dc voltage at the audio amplifier output without influencing the amplifier operation in the audio frequency range.

In this paper a low-pass filter is described with a very low cutoff frequency (< 5 Hz). Such a filter can be used as an offset cancelling circuit, but of course there are many other applications where low-frequency control loops are needed.

Straightforward RC techniques are incompatible with monolithic integration. For example, using an integrable capacitor of 50 pF, a cutoff frequency of 5 Hz requires a resistor value of 660 M Ω . Based on a sheet resistance of 200 $\Omega/\square$, and a resistor width/spacing of 5 μm , we would need a resistor 16 m long, requiring 160-mm² chip area.

Large on-chip time constants can be electronically synthesized; however, a common problem is the occurrence of large noise and offset voltages. Electronic enhancement of a time constant often means a multiplication of noise and

Fig. 1. Audio amplifier with gain defined by the resistor ratio of R_1 and R_2 .

offset by the same factor, thereby reducing the dynamic range of the filter [1]. The circuit approach described here does not suffer from noise and offset multiplication. Class AB operation is applied to avoid large noise and offset values caused by large quiescent currents. A low-pass filter has been realized with a -3 -dB frequency of approximately 3 Hz and an offset voltage of 2.5 mV using one on-chip capacitor of 50 pF and a total resistance value of 200 k Ω . The wide-band noise voltage at the output of the filter, which is the extra noise that appears at the output of an audio amplifier that is corrected by the circuit, amounted to 0.15-mV rms over the frequency range of 10 Hz to 30 kHz.

The paper is organized as follows. Section II explains the principle of the circuit. In Section III, the major building block is described—a $V-I$ converter with a very large input voltage range and low offset and transconductance. Section IV deals with the required attenuation of current using special current mirrors. The complete circuit is described in Section V. Measurement results are presented in Section VI for the circuit used as a low-pass filter and connected to an audio amplifier as an offset cancelling circuit. It is shown here that two large external electrolytic capacitors can be eliminated through use of a single integrated time constant. Finally, some conclusions are presented in Section VII.

II. CIRCUIT PRINCIPLE

Fig. 2 shows the principle of an audio amplifier with an offset cancelling circuit. The closed-loop gain in the audio frequency range is determined by the resistors R_1 and R_2 . The voltage at the output of the amplifier is converted to a small proportional current. This current is fed to a Miller integrator. The integrated current results in a voltage u_{corr} which is used to correct the offset voltage of the amplifier by adjusting its dc bias. It is assumed that a change Δu_{corr} in u_{corr} causes a change $\alpha \cdot \Delta u_{corr}$ in u_{out} .

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Fig. 2. Audio amplifier with an offset cancelling circuit.

Fig. 3. Closed-loop gain plot of the audio amplifier with offset cancelling circuit.

Fig. 3 shows the voltage gain of the circuit as a function of frequency. The frequency $f_{-3\text{ dB}}$ in the diagram is equal to

$$f_{-3\text{ dB}} = \frac{1 + \alpha \cdot h_{fe} \cdot R_p \cdot g}{2\pi \cdot h_{fe} \cdot R_p \cdot C} \approx \frac{\alpha \cdot g}{2\pi \cdot C}, \quad (\alpha \cdot h_{fe} \cdot R_p \cdot g \gg 1). \quad (1)$$

The offset voltage at the output of the circuit is given by

$$u_{\text{out, offset}} = \frac{R_1 + R_2}{R_2 \cdot (1 + \alpha \cdot h_{fe} \cdot R_p \cdot g)} \cdot u_{\text{offset1}} + u_{\text{offset2}}. \quad (2)$$

The offset cancelling circuit should not influence the amplifier behavior in the audio frequency range. Therefore $f_{-3\text{ dB}}$ should be below 10 Hz. So, for an integrated capacitor C , the transconductance g must be extremely small.

As mentioned before, electronic enhancement of a time constant often means a multiplication of noise and offset by the same factor. To avoid noise and offset multiplication, it is necessary that any signal attenuation is attended by a noise and offset attenuation by the same factor. So, a small transconductance g cannot be realized by subtracting the output currents of two $V-I$ converters with slightly different transconductances g_1 and g_2 . In that case, the resulting transconductance g would be $g_1 - g_2$, but the noise and offset of the two $V-I$ converters will in general not compensate each other. For the same reason, it is impossible to use a resistive divider at the input of the $V-I$ converter to attenuate the input voltage. In that case,

Fig. 4. The influence of α on $f_{-3\text{ dB}}$.

both the offset and noise of the converter increase relative to the signal by the same factor.

So, in order to minimize any offset multiplication, the input stage of the $V-I$ converter should be able to handle the input voltages, which are nearly as high as the supply voltage, directly. In that case it is necessary to use class (A)B operation. Otherwise, the offset will be very high. This can be seen as follows. Without class (A)B operation, the quiescent currents in the circuit have to be at least as large as the maximum possible signal currents. Therefore the quiescent currents in the output stage of the $V-I$ converter will be at least $g \cdot V_S/2$ (V_S = supply voltage). Each percent error in the value of the current as a result of device inequalities will cause an extra offset equal to

$$\Delta u_{\text{out, offset}} = \frac{0.01 \cdot g \cdot V_S}{2 \cdot g} = 0.01 \cdot V_S/2. \quad (3)$$

For a supply voltage of 10 V this is already 50 mV. If class (A)B operation is used, the quiescent currents can be considerably smaller. A relative error in these currents will therefore lead to a much smaller input offset voltage.

At first it seems from (1) that $f_{-3\text{ dB}}$ can be decreased by choosing α very small. However, it is of no use to make α smaller than 1, since this introduces low-frequency distortion. This can be seen as follows. Fig. 4 shows the voltage gains $|u_{\text{corr}}/u_{\text{out}}|$ and $|u_{\text{out}}/u_{\text{in}}|$ for $\alpha=1$ and $\alpha<1$. For $\alpha=1$, $f_{-3\text{ dB}}$ is equal to f_1 . If $\alpha<1$, $f_{-3\text{ dB}}$ will be smaller than f_1 . However, in that case the transfer ratio $|u_{\text{corr}}/u_{\text{out}}|$ becomes greater than 1 for all frequencies below f_1 . In practice, however, u_{corr} and u_{out} are both restricted by the supply voltage. Therefore, the u_{corr} signal will be hard-limited for low frequencies and large amplitudes of u_{out} . As a result, u_{out} gets distorted. It follows that the optimal value for α is 1.

Substituting the value of $\alpha=1$ in (1) and assuming a capacitor value of 50 pF gives the following condition for the transconductance g of the $V-I$ converter to yield $f_{-3\text{ dB}} < 10$ Hz:

$$g < \frac{2\pi \cdot k \cdot C \cdot f_{-3\text{ dB}}}{\alpha} \approx 3 \times 10^{-9} \text{ A/V}. \quad (4)$$

The current source I_0 should be proportional to the absolute temperature T and larger than the minimum value given by (8). For $R_E = 50 \text{ k}\Omega$ an acceptable value for I_0 is $35 \text{ }\mu\text{A}$ at $T = 300 \text{ K}$. From (5) it follows that I_1 and I_3 will be approximately $1.7 \text{ }\mu\text{A}$. So, the input offset voltage contribution caused by a 1-percent mismatch be-

Fig. 6. Transconductance of the V - I converter as a function of the input voltage over the range -2 to $+2$ V with (a) R_{lin} omitted, (b) $R_{lin} = 56$ k Ω , (c) $R_{lin} = 25$ k Ω , and (d) $R_{lin} = 10$ k Ω .

tween the emitter resistors R_E will be $0.01 \times 50 \times 10^{-3} \times 1.7 \times 10^{-3} = 0.85$ mV, which is acceptable.

The value of the base resistors R_B is not critical as long as the voltage drop across these resistors caused by the base current of T_2 is small. A mismatch in R_B does not cause an offset, although it causes asymmetrical output currents if an input signal is applied. For all measurements discussed below, we used a value of 7 k Ω .

Finally, the value of R_{lin} follows from (9) as approximately 60 k Ω .

C. Measurements

The V - I converter has been realized with our analog cell-based array (ACBA) semicustom chip [3], [4]. The resistors R_{lin} and R_E were connected externally to allow experimenting with their values. The differential output current $I_{out1} - I_{out2}$ and the transconductance have been measured as a function of the differential input voltage. The value of V_{REF} was chosen equal to V_S , which was 18 V (the maximum voltage allowed by the process).

The maximum allowable input voltage approximately equals the supply voltage. If a symmetrical input voltage is applied, signal amplitudes up to $36 V_{pp}$ are possible. The circuit is well suited to be connected to the output of an audio amplifier. The transfer is linear, except for around the origin. Fig. 6 shows a plot of the measured transconductance g over the input voltage range -2 to $+2$ V for various values of R_{lin} . For $R_{lin} = 56$ k Ω , we see that the small-signal transconductance is approximately equal to the large-signal transconductance, as expected. However, g still varies approximately 15 percent with minima at $|u_{in}| \approx 0.4$ V.

The input offset voltage was measured for a small number of samples and amounted to approximately 0.5 mV.

IV. ATTENUATING CURRENT MIRRORS

As stated in Section II the transconductance of the V - I converter should be less than 3×10^{-9} A/V. The transconductance of the circuit described in the previous section is

Fig. 7. Attenuating current mirrors with a control circuit.

Fig. 8. Measured input-to-output current relation of (a) a p-n-p and (b) a combined p-n-p/n-p-n attenuating current mirror with $U = 175$ mV.

approximately equal to 1×10^{-5} A/V, so a further current attenuation by at least a factor 3300 is needed. In this section a pair of attenuating current mirrors is described which can be used for this purpose.

Fig. 7 shows the schematic of the current mirrors and a control circuit. The current mirrors consist of n-p-n input (T_{18}, T_{19}) and p-n-p output transistors (T_{20}, T_{21}). The control circuit behaves like a voltage source U at the emitters of the output transistors. The use of p-n-p output transistors makes it possible to use a n-p-n current mirror following the circuit. The latter is important because the output currents of the circuit are very small and a p-n-p current mirror would perform much worse, particularly with respect to leakage currents.

P-n-p input transistors could not be used because their voltage-to-current relation is not truly exponential for currents larger than 10 μ A. This is illustrated by Fig. 8. The figure shows the measured current attenuation for a p-n-p and a combined n-p-n/p-n-p current mirror with a constant voltage source at the emitter of the output transistor. The p-n-p mirror is highly nonlinear because lateral p-n-p transistors behave as if resistors are placed in series with their emitters (high injection). This effect is negligible if the combined mirror is used.

Fig. 10. Offset cancelling circuit connected as a low-pass filter.

effects in the current mirror caused by class AB operation of the $V-I$ converter. This improves the circuit performance with respect to large-signal distortion.

The circuit was both breadboarded and integrated on our semicustom ACBA [3], [4]. An on-chip capacitor of 50 pF was used. The emitter resistors R_{E1} and R_{E2} and the linearizing resistor R_{lin} were connected externally to allow experimenting with their values. The attenuating current mirrors were dimensioned to attenuate by a factor 6000 by choosing $m=10$, $n=10$, $r=10$, and $p=5$ (see (13)). Therefore the total transconductance g of the $V-I$ converter is expected to be 1.7×10^{-9} A/V. The quiescent values of the output currents of the attenuating current mirrors are very small (≈ 0.3 nA). These currents can be increased while maintaining the same -3 -dB frequency and offset if a larger integrating capacitor is allowed.

VI. EXPERIMENTAL RESULTS

A. Low-Pass Filter Application

The circuit in Fig. 9 has been tested on its own by connecting the output u_{corr} to the inverting input as shown in Fig. 10. In that case the circuit behaves like a first-order low-pass filter. The offset voltage and -3 -dB frequency of this filter are equal to $u_{offset 2}$ and $f_{-3\text{ dB}}$ in Section II of this paper. All measurements were carried out at a supply voltage of 18 V, which was the maximum allowable voltage for the process used.

The total current consumption of the circuit with no signal applied was approximately 1.1 mA, of which 1 mA was caused by the current source I_1 in the output buffer.

The value of $u_{offset 2}$ has been measured for different values of u_{in} as the difference $u_{in} - u_{corr}$. The offset voltage was approximately 2.5 mV over the entire output range (approximately -7 to $+6$ V with respect to $V_S/2$; determined by the output stage).

The voltage gain of the circuit has been measured as a function of the frequency. This has been done for the filter in two ways: 1) with u_{corr} connected directly to the inverting input, and 2) with a voltage buffer (LM310) connected in series with u_{corr} . The results are shown in Fig. 11. The measurements without the voltage buffer show that the output stage of the circuit is not well suited to drive the inputs directly since the input signal feeds through to the output via the base resistors R_B (see Fig. 9). However, this is not very important in our case, because if the circuit is used as an offset cancelling circuit the inputs will be driven by the audio-amplifier output which has a very low output resistance. The -3 -dB frequency was measured as 3 Hz. This is less than the value expected from (1).

Fig. 11. Measured closed-loop gain of the low-pass filter as a function of frequency.

Fig. 12. Measured temperature dependence of (a) $f_{-3\text{ dB}}$ and (b) the offset voltage.

Due to the current mirror T_{24}/T_{25} the circuit is not fully symmetrical and a dc component occurs at the output if a signal is applied (signal-dependent offset). The gain of the current mirror is slightly less than unity because of the base currents so a positive offset $u_{in} - u_{out}$ can be expected, dependent on the amplitude of the input signal. This dc component has been measured as a function of the input signal amplitude and frequency. The results showed that for frequencies below 10 kHz the dc component increases approximately linearly (12 mV/V) with the input signal amplitude. For frequencies above 10 kHz the offset voltage increases more than linearly.

The dependence of $f_{-3\text{ dB}}$ and $u_{offset 2}$ on temperature has also been measured. The results are shown in Fig. 12. The -3 -dB frequency only decreases slightly over the temperature range from 20 to 120°C. $u_{offset 2}$ remains substantially constant up to 110°C and increases slightly up to a value of 4 mV at 120°C. For higher temperatures the leakage currents (especially the collector to substrate leakage currents in T_{24} and T_{25}) increase to the same order of magnitude as the collector currents of $T_{20}-T_{23}$ (≈ 0.3 nA) and then the offset increases drastically.

Finally, the rms amplitude of the wide-band noise voltage and the noise spectrum at the output of the filter have been measured. The rms amplitude amounted to approximately 0.15 mV over the frequency range of 10 Hz to 30 kHz. The measured noise spectrum is shown by graph 1 in Fig. 13. It can be seen that the noise level increases

Fig. 13. Measured noise spectrum at the output of the filter for three different values of bias current in the Miller integrator.

Fig. 14. Offset cancelling circuit connected to an audio amplifier.

significantly for frequencies below 10 kHz. It has been found that this is caused by the low current level in the Miller integrator. This current was increased by connecting an extra current source to the emitter of T_{29} . The rise in offset caused by this was then compensated by adding two current sources to the emitters of T_{18} and T_{19} . Graphs 2 and 3 in Fig. 13 show the noise spectrum for current levels in the Miller integrator of two and four times the normal level, respectively. The low-frequency noise level decreases considerably. However, the rms amplitude of the wide-band noise voltage over the frequency range of 10 Hz to 30 kHz only decreases slightly because of the increase of higher frequency noise components. The noise at the output of the filter will appear at the output of an audio amplifier which is corrected by the offset cancelling circuit.

B. Offset Correction Application

The circuit has also been tested in combination with operational amplifiers. Fig. 14 shows how the circuit was connected to the amplifiers. A dual supply voltage was used. Measurements have been carried out with a 741 operational amplifier and a TDA1514 integrated high-quality audio amplifier [6] at a closed-loop gain of 100 and 32, respectively. In both cases the closed-loop gain was measured as a function of frequency. The results are shown in Fig. 15. The effect of the offset cancelling circuit is exactly as expected: the gain decreases for low frequencies. The -3 -dB frequency has been measured as 3 Hz. This is the same as in the case that the circuit is connected as a low-pass filter.

The dc offset voltage became in both cases approximately 2.5 mV, as in the low-pass filter application. A dc voltage at the input of the amplifier hardly affected the offset voltage up to the value where u_{corr} gets limited by

Fig. 15. Measured closed-loop gain characteristic of a 741 operational amplifier and a TDA1514 audio amplifier used in the circuit of Fig. 14.

Fig. 16. Example of a circuit where two large electrolytic capacitors are eliminated through the use of the offset cancelling circuit.

the supply voltage. Without the offset cancelling circuit the 741 operational amplifier had an output offset voltage of 150 mV and the TDA1514 had an output offset of 80 mV. If a signal is present at the amplifier output a dc component occurs as could be expected from the measurements on the offset cancelling circuit connected as a low-pass filter. The rise in signal-dependent offset shown for frequencies above 10 kHz does not occur in the circuit with the 741 operational amplifier, because the gain for those frequencies is already very small. The effect did occur in the circuit with the TDA1514 amplifier. If high-frequency components are present in the audio signal, special measures should be taken to prevent those components from reaching the input of the offset cancelling circuit. A possible solution would be to place a 10-kHz low-pass filter in front of the circuit.

If the offset cancelling circuit is used as shown in Fig. 14 one electrolytic capacitor normally placed in series with R_2 is eliminated (see also Fig. 1). Fig. 16 shows that for amplifiers with a single supply voltage a second electrolytic capacitor normally connected between node X and ground to obtain a stable $V_S/2$ voltage can also be eliminated. However, the audio-amplifier inputs should be able to handle signals near ground potential. The closed-loop gain of the audio amplifier is defined by the resistors R_1 and R_2 , as in Fig. 14. The output voltage of the offset cancelling circuit is now connected to the noninverting input of the audio amplifier via a resistive divider (R_3 , R_4). The ratio R_3/R_4 has to be equal to R_1/R_2 to realize a factor α (see Section II) equal to unity. The input signal is con-

nected to R_4 and is therefore slightly attenuated by the divider R_3, R_4 . The offset cancelling circuit will keep the output of the audio amplifier at half the supply voltage, due to the divider R_5/R_6 . Ripple on the supply voltage will be filtered, just as the output signal of the amplifier. The circuit was constructed with a CA3140 operational amplifier representing the audio amplifier and $R_1 = R_3 = 26 \text{ k}\Omega$, $R_2 = R_4 = 820 \Omega$, and $R_5 = R_6 = 1 \text{ k}\Omega$. A 100-Hz ripple on the supply voltage V_S appeared at the output attenuated by 37 dB as could be expected from Fig. 11 if the factor 2 attenuation of the voltage divider R_5, R_6 is also taken into account.

VII. CONCLUSION

A monolithic offset cancelling circuit to reduce the offset voltage at an integrated audio-amplifier output has been described. It has been shown that a -3-dB frequency below 5 Hz can be achieved using only one small on-chip capacitor of 50 pF and a total resistance value of 200 k Ω . The resulting offset voltage at the audio-amplifier output was approximately 2.5 mV and remained small up to a temperature of 120°C. For higher temperatures the leakage currents increase to the same order of magnitude as some of the quiescent currents and the offset rises drastically. The rms amplitude of the extra noise caused by the circuit at the audio-amplifier output amounts to approximately 0.15 mV over the frequency range of 10 Hz to 30 kHz. The circuit approach described is capable of handling large input voltages, restricted only by the supply voltage.

If the circuit is used in combination with an audio amplifier the capacitor usually used in the feedback loop to eliminate dc gain will be eliminated. If the dc voltage at the output of the circuit preceding the audio amplifier is not too large, the input capacitor can also be omitted. In addition, for amplifiers with a single supply voltage, a second capacitor used to obtain a stable $V_S/2$ voltage can be eliminated.

The circuit has a disadvantage in the form of a signal-dependent offset. A sinusoidal signal applied to the input of the circuit gives rise to a dc component at the output equal to approximately 1.2 percent of the signal amplitude because the circuit is not fully symmetrical. For signal frequencies above about 10 kHz the signal-dependent offset rises significantly and if the circuit is to be used in high-quality equipment, measures should be taken to prevent high-frequency signals from reaching the circuit input. A possible solution would be to place a 10-kHz low-pass filter in front of the circuit.

It might very well be possible to improve the circuit. The major cause for the signal-dependent offset are the base currents in the current mirror T_{24}/T_{25} . An extra transistor could be used to decrease this effect. In that case it might also be advantageous to interchange the collectors and emitters of T_{24} and T_{25} . This will eliminate the collector-to-substrate leakage and decrease the collector-to-base leakage currents. In addition, parasitic capacitances will become smaller which probably improves the circuit behavior above 10 kHz.

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